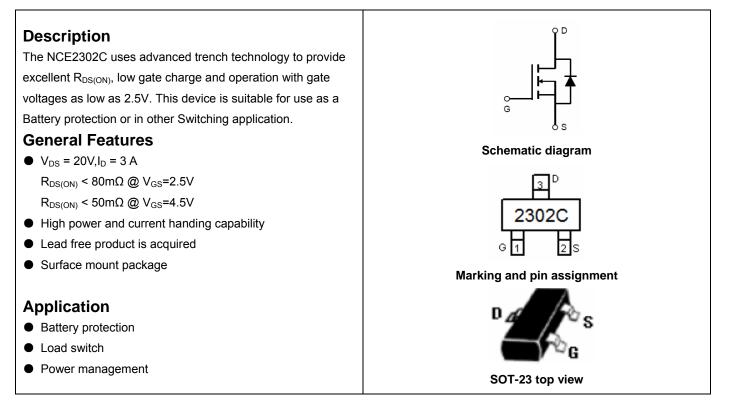


NCE N-Channel Enhancement Mode Power MOSFET



Package Marking and Ordering Information

	<u> </u>	V			
Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
2302C	NCE2302C	SOT-23	Ø180mm	8 mm	3000 units

Absolute Maximum Ratings (T_A=25℃ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	20	V
Gate-Source Voltage	Vgs	±12	V
Drain Current-Continuous	I _D	3.0	A
Drain Current-Pulsed (Note 1)	I _{DM}	12	A
Maximum Power Dissipation	PD	0.8	W
Operating Junction and Storage Temperature Range	T _J ,T _{STG}	-55 To 150	°C

Thermal Characteristic

Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta JA}$	156	°C/W

Electrical Characteristics (T_A=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V Ι _D =250μΑ	20	22	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =20V, V_{GS} =0V	-	-	1	μA



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Parameter	Symbol	Condition	Min	Тур	Max	Unit
Gate-Body Leakage Current	I _{GSS}	V_{GS} =±12V, V_{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)						•
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	0.5	0.75	1.2	V
Drain Courses On State Desistence	5	V _{GS} =2.5V, I _D =2.8A	-	42	80	mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =4.5V, I _D =3A	-	35	50	mΩ
Forward Transconductance	g fs	V _{DS} =5V,I _D =3A	-	5	-	S
Dynamic Characteristics (Note4)				•		
Input Capacitance	C _{lss}		-	240	-	PF
Output Capacitance	Coss	V _{DS} =10V,V _{GS} =0V, F=1.0MHz	-	45	-	PF
Reverse Transfer Capacitance	C _{rss}		-	23	-	PF
Switching Characteristics (Note 4)				•		
Turn-on Delay Time	t _{d(on)}	V _{DD} =10V, R _L =3.3Ω	-	2.3	-	nS
Turn-on Rise Time	tr		-	3.1	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =4.5V, R_{GEN} =6 Ω	-	20	-	nS
Turn-Off Fall Time	t _f		-	2.5	-	nS
Total Gate Charge	Qg	V _{DS} =10V,I _D =3A, V _{GS} =4.5V	-	2.7	5	nC
Gate-Source Charge	Q _{gs}		-	0.4	-	nC
Gate-Drain Charge	Q _{gd}	V _{GS} -4.5V	-	0.5	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =3A	-	-	1.2	V
Diode Forward Current (Note 2)	I _S		-	-	3	А

Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board, $t \le 10$ sec.
- **3.** Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.
- 4. Guaranteed by design, not subject to production



NCE2302C



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Typical Electrical and Thermal Characteristics

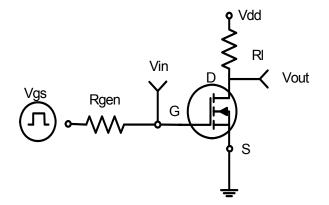
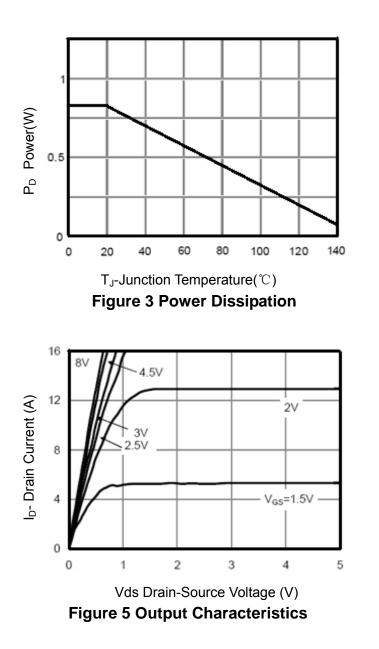
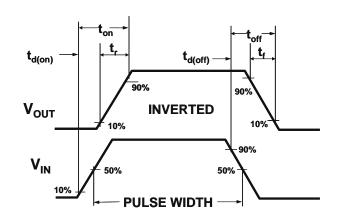


Figure 1:Switching Test Circuit







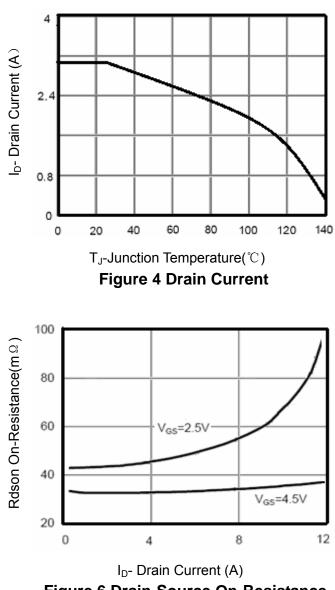


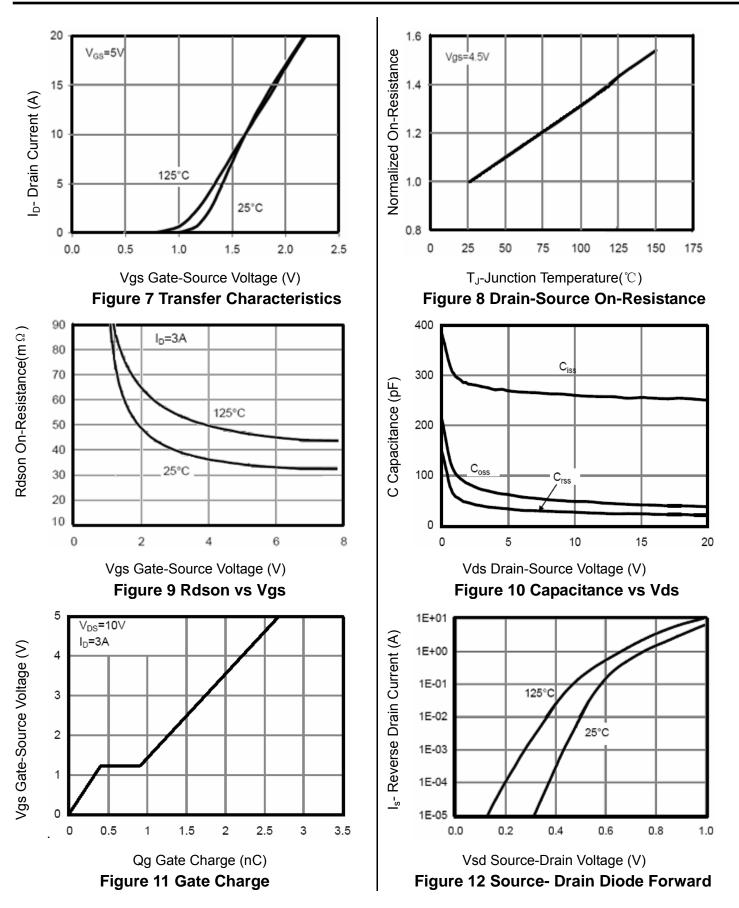
Figure 6 Drain-Source On-Resistance



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Pb Free Product

NCE2302C





₩

0.001

0.01

0.1

Square Wave Pluse Duration(sec) Figure 14 Normalized Maximum Transient Thermal Impedance

1

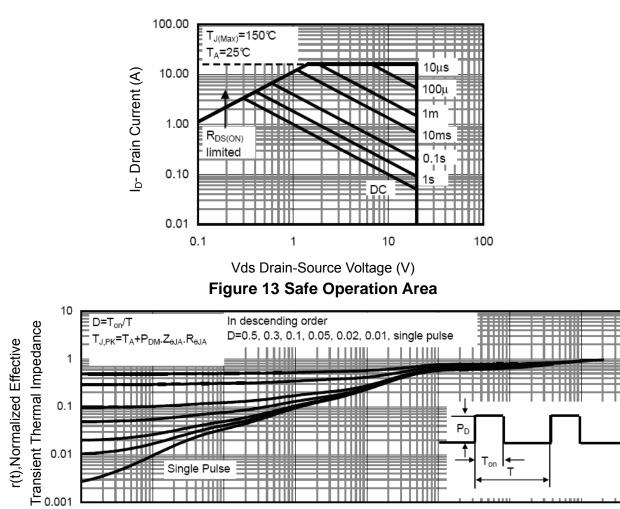
10

100

1000

0.0001





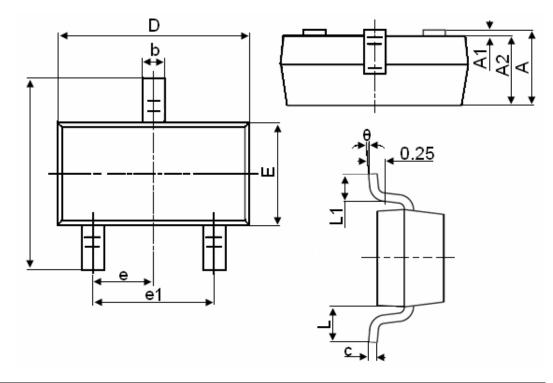
0.00001



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SOT-23 Package Information



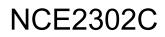
Symbol	Dimensions in Millimeters				
Symbol	MIN.	MAX.			
A	0.900	1.150			
A1	0.000	0.100			
A2	0.900	1.050			
b	0.300	0.500			
с	0.080	0.150			
D	2.800	3.000			
E	1.200	1.400			
E1	2.250	2.550			
е		0.950TYP			
e1	1.800	2.000			
L	0.550REF				
L1	0.300	0.500			
θ	0°	8°			

Notes

- 1. All dimensions are in millimeters.
- 2. Tolerance ±0.10mm (4 mil) unless otherwise specified
- 3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
- 4. Dimension L is measured in gauge plane.
- 5. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.







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